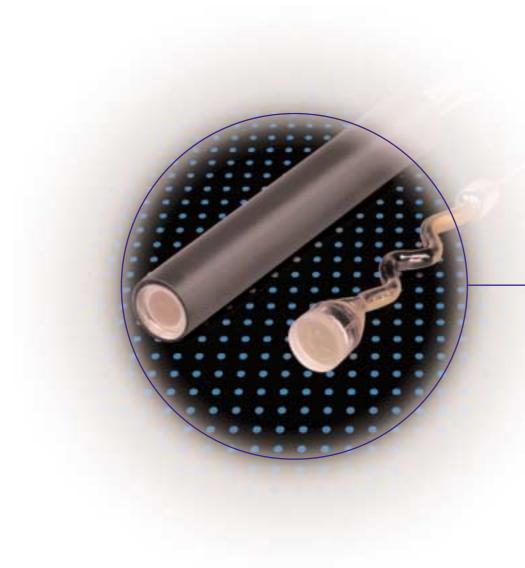


Channel Photomultipliers Overview and Specifications





CHANNEL PHOTOMULTIPLIER







Features

- Ultra high anode sensitivity up to 10⁷ A/W
- Extremely low dark current, typically 3pA @ 10⁶ gain
- Very low equivalent noise input (down to 10⁻¹⁷ W)
- Very high stability in dark current (no "bursts")
- High gain exceeding 10⁸
- Very high dynamic range
- Compact dimensions
- Wide spectral response through multiple window materials
- High resolution
- Fast response time
- High immunity to magnetic fields
- Rugged design

Description

PerkinElmer Optoelectronics, formerly EG&G Optoelectronics, is pleased to introduce the Channel Photomultiplier (CPM), a new ultra high sensitivity optical detector which replaces conventional photomultipliers (PMTs) and avalanche photo diodes (APDs). This device uses a unique detector principle, resulting in a compact design with ultra high gain, high dynamic range, extremely low dark current, and fast response.

This high-performance detector offers fundamental advantages for analytical instrumentation applications such as emission spectroscopy, flourescence, atomic absorption spectroscopy, and bio and chemo luminescence. The CPM also delivers important advantages in life science products, industrial and medical equipment, and highenergy physics.

When compared to conventional PMTs, the CPM improves anode sensitivity by one order of magnitude, while lowering dark current by one to two orders of magnitude. The noise level shows extreme stability over time, with no "bursts." The extremely low dark current results in a higher dynamic range than conventional PMTs and extends detectable limits for many applications.

The CPM can be used in analog-DC mode, single photon counting mode, and in nuclear spectroscopy (when coupled to scintillation materials like BGO, LSO, Nal, etc.). PerkinElmer Optoelectronics offers a choice of window materials and photocathodes to cover the spectrum from 115 nm (UV range) to 900 nm (NIR).

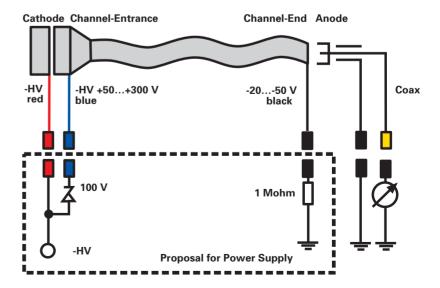
The new detector is a small, head-on type with a total diameter of 10.5 mm including encapsulation. PerkinElmer Optoelectronics also offers custom configurations for specific applications.

PRINCIPLE OF OPERATION

Principle of Operation

The CPM, like conventional photomultiplier tubes, converts a very low light level into photoelectrons by a semitransparent photocathode deposited on the inner surface of the entrance window. On their way from the cathode to the anode the photoelectrons pass through a narrow, semiconductive channel. Each time the electrons hit the inner wall of the curved channel, multiple secondary electrons are emitted. This effect occurs multiple times along the path, leading to an avalanche effect with a gain exceeding 108. The curved shape of the glass tube improves the multiplication effect.

Physical Specification

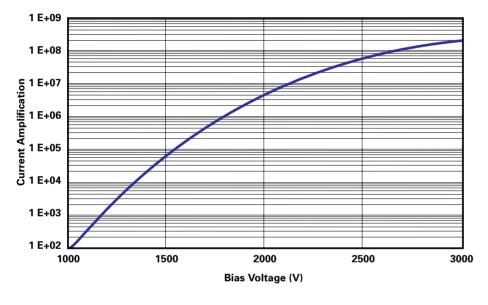


MAIN FEATURES



Unpotted 1/3 inch Channel Photomultiplier

Fig. 1: Typical current amplification



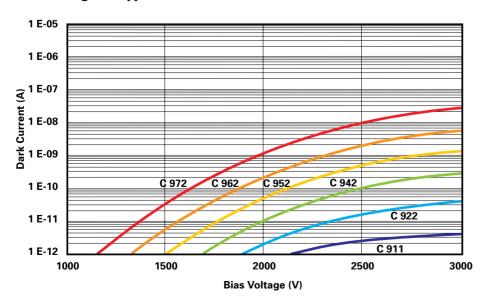
Compact Size

The CPM is one of the smallest headon type detectors, with a 10.5 mm diameter including encapsulation. The photocathode has a useful diameter of more than 5 mm. The tube is smaller, easier to use, and more rugged than discrete dynode types. Only a single high voltage supply of up to 3000 volts is necessary; no external voltage divider network is required. A variety of different sizes will be available soon (1/2" and 3/4").

Ultra high anode sensitivity

At the maximum bias voltage of 3000 V, gains can exceed 10°. At 2400 V, anode sensitivity is typically 3 x 10° AWV at a wavelength of 410 nm with a bialkali photocathode. This performance surpasses conventional PMTs by one to two orders of magnitude and beats APDs by approximately five orders of magnitude (Fig. 1).





Extremely low dark current

The electron multiplication in the channel is virtually silent, so dark current depends only on the photocathode material, leakage currents are negligible. Bialkali photocathodes exhibit typical dark count rates of 10 cps at a gain of 3 x 108, while UV cathodes have dark count rates below 1 cps. In analog DC mode, the typical dark noise for a bialkali photocathode is 20 pA at a gain of 107. In general, the noise level of the PerkinElmer Optoelectronics CPM is one to two orders of magnitude lower than dynode PMTs, resulting in a significantly higher dynamic range (Fig.2).

High stability in dark current level

As a result of the semiconductive inner surface of the CPM, no charge-up effects occur at the glass surface. This results in a very high stability of the dark current level over time, with no sudden changes (bursts). The semiconductive surface also causes high-light recovery times to be extremely small.

Fig. 3: Typical photo electron spectrum

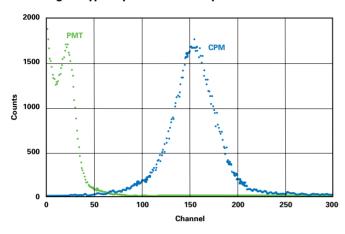


Fig. 4.1: Typical spectral response

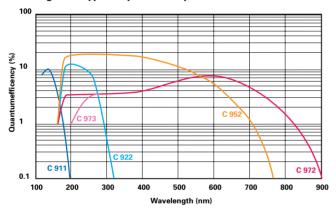
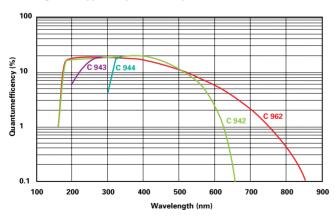


Fig. 4.2: Typical spectral response



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Excellent photon counting resolution

At gains exceeding 10⁷ the single photo electron pulse is perfectly separated from the electrical noise, due to a saturation effect of the channel. The CPM exhibits single photon resolution with excellent peak to valley ratios. Fig. 3 shows the single photo electron spectrum taken from a multi-channel analyzer compared to a conventional photomultiplier (Fig. 3).

Choice of entrance window

The CPM is available with different window materials, which are:

MgF₂, Quartz, UV-glass, and Borosilicate glass. The combination of different photocathodes and entrance windows results in a spectral range from 115 nm to 900 nm. Other window materials and photocathode combinations are available on a custom basis (Fig. 4.1 and 4.2).

Available related products

• High Voltage supply

CHV 30N (supplies 1 CPM, negative output voltage), CHV 30P (supplies 1 CPM, positive output voltage), J4-3N (supplies 10 to 15 CPMs)

CPM Modules

MP900-series: Photoncounting module with

TTL output, including CPM, electronic and high voltage

MD900-series: DC module including high

voltage supply, amplifier, I/U converter, output 0 to 10 V,

bandwidth 1kHz

MH900-series: High voltage module,

including CPM and

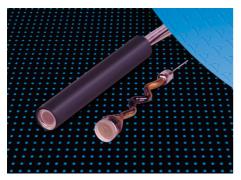
high voltage power supply

CPM Formats

1/3" C900-series 1/2" C1300-series 3/4" C1900-series

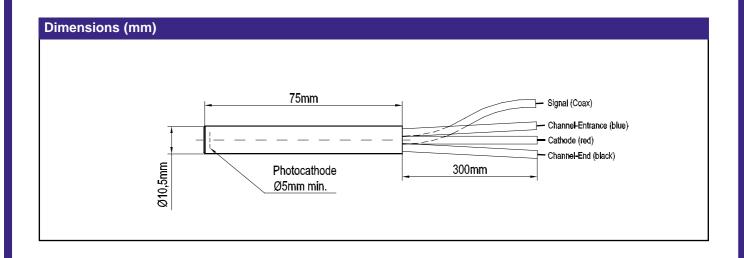
Datasheets on request

CPM C900 Series 1/3" **CPM Channel Photomultipliers**



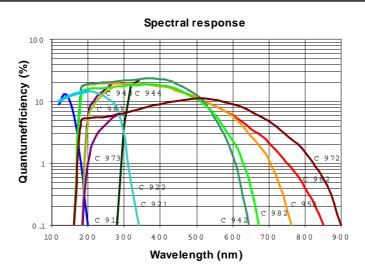
- · High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 1/3 Inch, Head-On Type

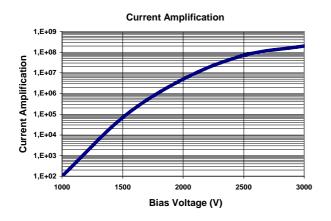
Technical Specifications																									
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 200 nm (A/W)	@ 400 nm (A/W)	@ 560 nm (A/W)	Dark current (pA)	Equivalent Noise Input, ENI (W)	Bias current (µA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)		
C911	115-200	Csl		MgF ₂				6x10 ⁵				2	1x10 ⁻¹⁷					C911P			0.1				
C921	115-320	CsTe		MgF ₂					x10 ⁶			10	1x10 ⁻¹⁷					C921P			1				
C922	165-320	CsTe		Quartz				1	x10 ⁶			10	1x10 ⁻¹⁷					C922P			1				
C942	165-650	Bial kali		Quartz				107				3x10 ⁶		80	1x10 ⁻¹⁷		뉟			C942P			10	1	
C943	185-650	3ia		UV glass							3x10 ⁶		80	1x10 ⁻¹⁷		nrre			C943P			10			
C944	300-650			Borosil.	plier				.007	_		3x10 ⁶		80	1x10 ⁻¹⁷		3S C	_		C944P			10		
C952	165-750	nois iialk		Quartz	lulti	00						3x10 ⁶		250	2.5x10 ⁻¹⁷		fbië	sec.)	C952P			40			
C953	185-750	Low noise Multialk.	2	UV glass	tron N	(max. 3000)						3x10 ⁶		80 1x10 ⁻¹⁷ 80 1x10 ⁻¹⁷ 250 2.5x10 ⁻¹⁷	C953P	3000	3x10 ⁸	40	10:1	50					
C962	165-850	Multialk.	,	Quartz	Channel Electron Multiplier					2:	к10 ⁶	1000	00 4x10 ⁻¹⁷ 00 01 (iiiii) 01 01 02 000 00 00 00 00 00 00 00 00 00 00 00	C962P	(max. 3000	3,	100	10	5						
C963	185-850	Mu		UV glass	anne	2400				2:	к10 ⁶	1000	4x10 ⁻¹⁷		(DC linearity limit)	10 µ		C963P	3000 (n		100				
C972	165-900	Extend. red Multialk.		Quartz	ဉ်					2:	x10 ⁶	5000	1.5x10 ⁻¹⁶		C line			C972P	30		500				
C973	185-900	Mul a		UV glass						2:	к10 ⁶	5000	1.5x10 ⁻¹⁶		0	.		C973P			500				
C982	165-650	¥ se ≼		Quartz						3x10 ⁶		25	6x10 ⁻¹⁸					C982P			3				
C983	185-650	Low noise Bialk.		UV glass						3x10 ⁶		25	6x10 ⁻¹⁸					C983P			3				

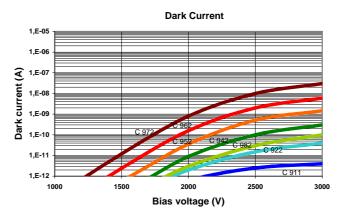


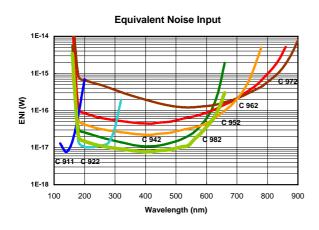
CPM C900 Series1/3" **CPM Channel Photomultipliers**

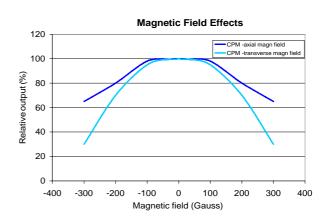
CPM C900 Performance Specifications









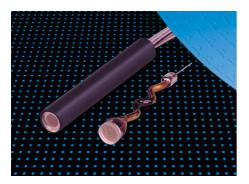


CAUTION: High Voltage Warning!

This product is operated at high voltage. Extreme care must be taken to ensure operator safety and to avoid damage to other instruments. Avoid direct contact with the photomultiplier when high voltage is applied. Avoid placing conductive material close to the cathode.

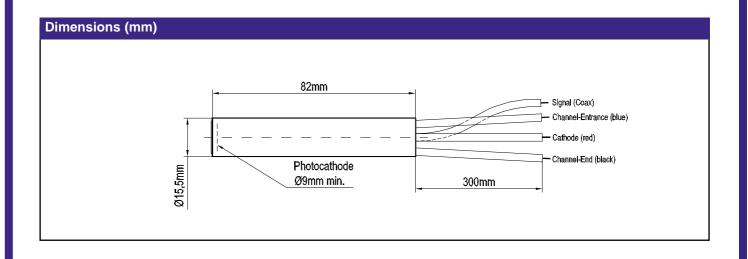
All given values are nominal/typical @ 20 °C ambient temperature; specifications subject to change without notice.

CPM C1300 Series 1/2" **CPM Channel Photomultipliers**



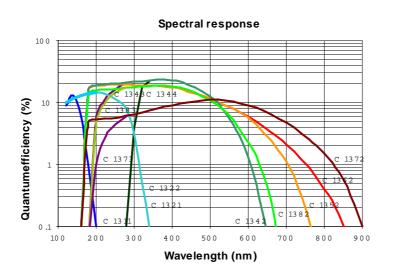
- High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 1/2 Inch, Head-On Type

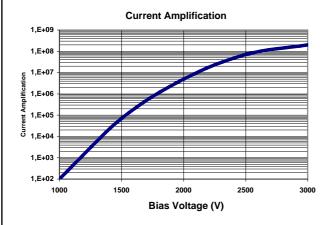
Technical Specifications																														
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 400 nm (A/W)	@ 560 nm (A/W) Dark current (pA)	Equivalent Noise Input, ENI (W)	Bias current (IIA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)									
04044	445.000	0-1		MF				0405			0.40:1	7				C4244B			0.4											
C1311	115-200	Csl		MgF ₂				6x10 ⁵ 1x1	06	8	2x10 ⁻¹					C1311P			0.4											
C1321 C1322	115-320 165-320	CsTe CsTe		MgF ₂ Quartz			5×10 ⁷	1x1	06	40	2x10 ⁻¹ 2x10 ⁻¹					C1321P C1322P	-		4											
C1342	165-650			Quartz					3x10 ⁶	320						C1342P			40											
C1343	185-650	Bial kali		UV glass					3x10 ⁶	320		7	lent			C1343P			40											
C1344	300-650	Bia		Borosil.	1			5x10 ⁷										3x10 ⁶	320			15			C1344P			40		
C1352	165-750	Low noise Multialk.		Quartz		3000)				3x10 ⁶	100	4x10 ⁻¹	7	(DC linearity limit) 10% of bias current	10 µA (max. 30 sec.)		C1352P	00)		160										
C1353	185-750		6	UV glass		ä.			5x10 ⁷	۲10'		3x10 ⁶	100	4x10 ⁻¹	- 2	3 Š	ax.	ကမ	C1353P	3000	3x10 ⁸	160	10:1	20						
C1362	165-850	ak K		Quartz		E					2x1	06 400	8x10 ⁻¹	7	liif)	Ë		C1362P		ř	400	_								
C1363	185-850	Multialk.		UV glass		2400 (max.			2x1	0 ⁶ 400			arity li	10 µ/		C1363P	3000 (rr		400											
C1372	165-900	Extend. red Multialk.		Quartz					2x1	0 ⁶ 2000	0 3x10 ⁻¹	6	OC line			C1372P	30		2000											
C1373	185-900	Ă_b		UV glass					2x1	06 2000	0 3x10 ⁻¹	6	=	9		C1373P			2000											
C1382	165-650	≱ se ≩		Quartz					3x10 ⁶	100	1x10 ⁻¹	7				C1382P			10											
C1383	185-650	noi: Bial	Low noise Bialk.	Lo nois Bial		UV glass					3x10 ⁶	100						C1383P			10									

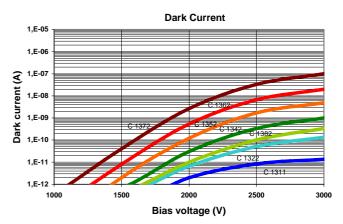


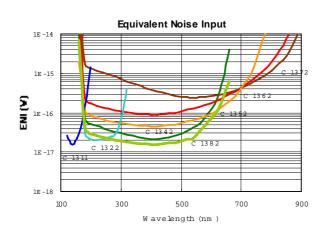
CPM C1300 Series1/2" **CPM Channel Photomultipliers**

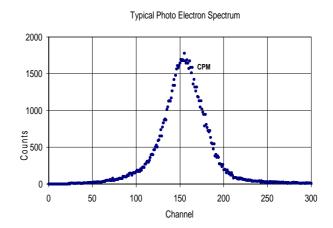










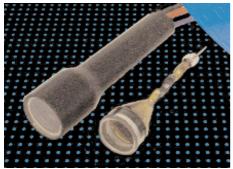


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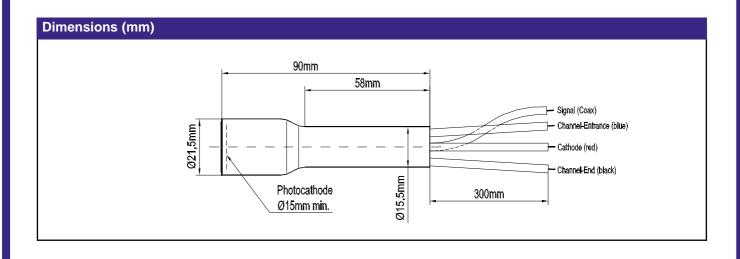
All given values are nominal/typical @ 20 °C ambient temperature; specifications subject to change without notice.

CPM C1900 Series 3/4" **CPM Channel Photomultipliers**



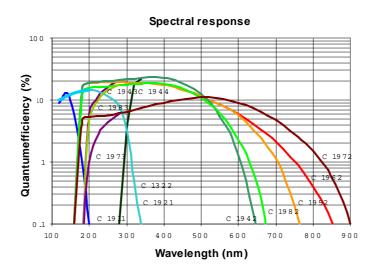
- · High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 3/4 Inch, Head-On Type

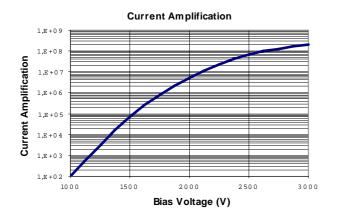
Techi	nical Sp	ecific	atio	ons																															
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 200 nm (A/W)	@ 400 nm (A/W)	@ 560 nm (A/W) Dark current (pA)		Equivalent Noise Input, ENI (W)	Bias current (µA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)												
C1911	115-200	Csl		MgF ₂				6x10 ⁵			20	-	3x10 ⁻¹⁷					C1911P			1														
C1921	115-320	CsTe		MgF ₂	-				x10 ⁶		100	\rightarrow	3x10 ⁻¹⁷					C1921P			10														
C1922	165-320	CsTe		Quartz				1	x10 ⁶		100	\neg	3x10 ⁻¹⁷					C1922P	+		10														
C1942	165-650	ka		Quartz	-																3x10 ⁶		800	-	3x10 ⁻¹⁷		Ħ			C1942P			100	-	
C1943	185-650	Bial kali	-	UV glass																						3x10 ⁶	800	_	3x10 ⁻¹⁷	l e	ırre			C1943P	
C1944	300-650			Borosil.	Borosil.	je.				3	х10 ⁶	800	0	3x10 ⁻¹⁷		เร	_		C1944P			100													
C1952	165-750	Low noise Multialk.		Quartz	Multip	(000	5x10 ⁷									3	x10 ⁶	250	0	8x10 ⁻¹⁷	of bia	sec.)		C1952P			400								
C1953	185-750	Low	13	UV glass	tron !	ax. 3(3	x10 ⁶	250	0	8x10 ⁻¹⁷	50	0%0		e 3	C1953P	3000)	3x10 ⁸	400	Σ	20												
C1962	165-850	Multialk.	7	Quartz		2400 (max. 3000)	2X			2x1	0 ⁶ 100	00	1x10 ⁻¹⁶	2	mit) 1	A (max.	., 0	C1962P		3x.	1000	10:1	2												
C1963	185-850	Mult		UV glass		240				2x1	0 ⁶ 100	00	1x10 ⁻¹⁶		arity I.	10 µA		C1963P	3000 (max.		1000														
C1972	165-900	tend. red ultialk.		Quartz	ర్					2x1	0 ⁶ 500	00	5x10 ⁻¹⁶		(DC linearity limit) 10% of bias current			C1972P	300		5000														
C1973	185-900	Extend. red Multialk.		UV glass							2x1	0 ⁶ 500	00	5x10 ⁻¹⁶		Ď			C1973P			5000													
C1982	165-650	Low noise Bialk.		Quartz															3	x10 ⁶	250	0	2x10 ⁻¹⁷					C1982P			25				
C1983	185-650	Bi Bi	Low noise Bialk.	Pia oi	noi Bia	noi Bia	noi Bia		UV glass					3	x10 ⁶	250	0	2x10 ⁻¹⁷					C1983P			25									

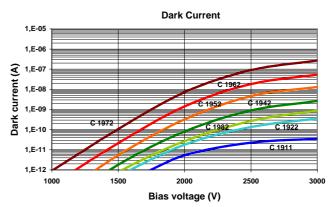


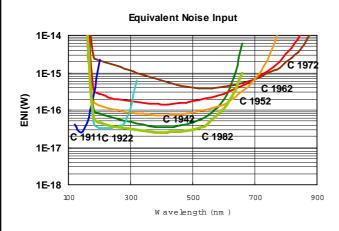
CPM C1900 Series 3/4" CPM Channel Photomultipliers

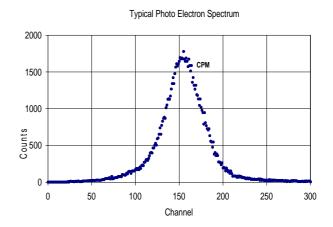
CPM C1900 Performance Specifications











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